SHANGHAI SINO-IC MICROELECTRONICS CO., LTD.

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SESD3Z08C Transient Voltage Suppressors for ESD Protection

Revision:A

General Description Features The SESD3Z08C is designed to protect voltage ulletSmall Body Outline Dimensions sensitive components from ESD and transient voltage • Low Body Height events. Excellent clamping capability, low leakage, and Peak Power up to 350 Watts @ 8 x 20 _µs Pulse • fast response time, make these parts ideal for ESD • Low Leakage current protection on designs where board space is at a Response Time is Typically < 1 ns • premium. ESD Rating of Class 3 (> 16 kV) per Human Body Model **Applications** Cellular phones Complies with the following standards Portable devices IEC61000-4-2 **Digital cameras** Level 4 15 kV (air discharge) Power supplies 8 kV(contact discharge) MIL STD 883E - Method 3015-7 Class 3 25 kV HBM (Human Body Model)

Functional diagram





SOD-323

Absolute Ratings (T _{amb} =25°C)							
Symbol	Parameter	Value	Units				
Р _{РК}	Peak Pulse Power (t _p = 8/20µs)	350	W				
TL	Maximum lead temperature for soldering during 10s	260	°C				
T _{stg}	Storage Temperature Range	-55 to +155	°C				
T _{op}	Operating Temperature Range	-40 to +125	°C				
TJ	Maximum junction temperature	150	°C				

Electrical Parameter

Symbol	Parameter				
I _{PP}	Maximum Reverse Peak Pulse Current				
Vc	Clamping Voltage @ IPP				
V _{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
Ι _τ	Test Current				
V_{BR}	Breakdown Voltage @ I _T				



Electrical Characte	Ratings at 25°C ambient temperature unless otherwise specified.						
		V_{BR}		Ι _Τ	V _{RWM}	I _R	С
Part Numbers	Min.	Тур.	Max.				Typ. (Note1)
	V	V	V	mA	V	μA	pF
SESD3Z08C	8.6	9.5	10.2	1	5	1	24

1. Capacitance is measured at f=1MHz, V_R =0V, T_A =25 °C.

Typical Characteristics



Application Note

Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS offers the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal lines to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground. The SESD3Z08C is the ideal board evel protection of ESD sensitive semiconductor components.

The tiny SOD-323 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening against ESD.

SOD-323 Mechanical Data



Dimensions							
Dim	Inc	hes	Mil				
	Min	Max	Min	Max			
А	0.060	0.071	1.5	1.8			
В	0.045	0.054	1.2	1.4			
С	0.060	0.107	2.3	2.7			
D	-	0.043	-	1.1			
E	0.012	0.016	0.3	0.4			
F	0.004	0.010	0.10	0.25			
Н	-	0.004	-	0.10			

CONTROLLILNG DIMENSION: MILLIMETERS

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